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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Manger Docket No.: INF-131  
Serial No.: 10/765,910 Art Unit: 2812  
Filed: January 29, 2004 Examiner: TBD  
For: FinFET Device and Method of Fabrication

**Certificate of Mailing via First Class Mail (37 C.F.R. § 1.8(a))**

Date of Deposit: September 8, 2004

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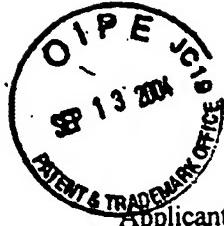
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IDS Combined Form PTO/SB/08a and 08b (1 page) citing (2) references  
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Respectfully submitted,

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Mail Stop: Amendment  
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Dear Sir:

Applicant wishes to bring to the attention of the Patent and Trademark Office the information noted on the enclosed combined form PTO/SB/08a & 08b that may be considered material to the examination of the above-identified application.

No fee is due at this time, as this Information Disclosure Statement is being filed pursuant to 37 C.F.R. § 1.97(b)(3), before the mailing of a first Office action on the merits.

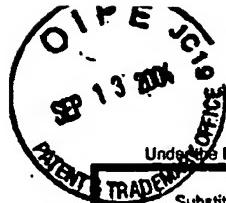
Respectfully submitted,

  
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September 8, 2004

Date

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PTO/SB/08a (08-03)

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<p><b>TRADEMA</b> Substitute for form 1449A/PTO</p> <p><b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b></p> <p><i>(Use as many sheets as necessary)</i></p>				<b>Complete if Known</b>	
				<b>Application Number</b>	10/765,910
				<b>Filing Date</b>	1/29/2004
				<b>First Named Inventor</b>	Manger
				<b>Art Unit</b>	2812
				<b>Examiner Name</b>	TBD
<b>Sheet</b>	1	<b>of</b>	1	<b>Attorney Docket Number</b>	INF-131

U.S. PATENT DOCUMENTS

## **FOREIGN PATENT DOCUMENTS**

FOREIGN PATENT DOCUMENTS					
Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Country Code <sup>3</sup> - Number <sup>4</sup> - Kind Code <sup>5</sup> (if known)			

## **NON PATENT LITERATURE DOCUMENTS**

Examiner Initials*	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
	2	YU, B., et al, "FinFET Scaling to 10nm Gate Length," IEDM, 2002, pp. 251-254.	

<b>Examiner Signature</b>		<b>Date Considered</b>	
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**\*EXAMINER:** Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. **'Applicant's unique citation designation number (optional).** **'See Kinds Codes of USPTO Patent Documents at [www.uspto.gov](http://www.uspto.gov) or MPEP 901.04.** **'Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3).** **'For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document.** **'Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible.** **'Applicant is to place a check mark here if English language Translation is attached.**

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